

USB2223-03



Bus Powered USB2.0 Flash Media Controller

Datasheet

Product Features

- Complete System Solution for interfacing SmartMediaTM (SM), Memory StickTM (MS), High Speed Memory Stick (HSMS), Memory Stick PROTM (MSPRO), Memory Stick DuoTM (MSDUO), Secure Digital (SD), Mini-Secure Digital (Mini-SD), Transflash (SD), MultiMediaCardTM (MMC), Reduced Size Multimedia Card (RS-MMC), NAND Flash, Compact FlashTM (CF), CF UltraTM I&II and CF form-factor ATA hard drives to USB2.0 bus.
 - Supports USB Bulk Only Mass Storage Compliant Bootable BIOS
- Support for simultaneous operation of all above devices. (only one at a time of each of the following groups supported: CF or ATA drive, SM or NAND, SD or MMC)
- On-Chip 4-Bit High Speed Memory Stick and MS PRO Hardware Circuitry
- On-Chip firmware reads and writes High Speed Memory Stick and MS PRO
- 1-bit ECC correction performed in hardware for maximum efficiency
- USB Bus Power Certified
- 3.3 Volt I/O with 5V input tolerance
- Complete USB Specification 2.0 Compatibility for Bus Powered Operation
 - Includes USB2.0 Transceiver
 - A Bi-directional Control and a Bi-directional Bulk Endpoint are provided.
- 8051 8 bit microprocessor
 - Provides low speed control functions
 - 30 Mhz execution speed at 4 cycles per instruction average
 - 12K Bytes of internal SRAM for general purpose scratchpad
 - 768 Bytes of internal SRAM for general purpose scratchpad or program execution while re-flashing external ROM

- Double Buffered Bulk Endpoint
 - Bi-directional 512 Byte Buffer for Bulk Endpoint
 - 64 Byte RX Control Endpoint Buffer
 - 64 Byte TX Control Endpoint Buffer
- Internal or External Program Memory Interface
 - 64K Byte Internal Code Space or Optional 64K Byte External Code Space using Flash, SRAM or EPROM memory.
- On Board 12Mhz Crystal Driver Circuit
- On-Chip 1.8V Regulator for Low Power Core Operation
- Internal PLL for 480Mhz USB2.0 Sampling, Configurable MCU clock
- Supports firmware upgrade via USB bus if "boot block" Flash program memory is used
- 15 GPIOs for special function use: LED indicators, button inputs, power control to memory devices, etc.
 - Inputs capable of generating interrupts with either edge sensitivity
 - Attribute bit controlled features:
 - Activity LED polarity/operation/blink rate
 - Full or Partial Card compliance checking
 - Bus or Self Powered
 - LUN configuration and assignment
 - Write Protect Polarity
 - Detach on no Card Inserted for Notebook apps
 - Inquiry Command operation
 - SD Write Protect operation
 - Older CF card support
 - Force USB 1.1 reporting
- Compatible with Microsoft WinXP, WinME, Win2K SP3, Apple OS10, Softconnex, and Linux Multi-LUN Mass Storage Class Drivers
- Win2K, Win98/98SE and Apple OS8.6 and OS9 Multi-LUN Mass Storage Class Drivers available from SMSC
- 128 Pin TQFP Package (1.0mm height, 14mm x14mm footprint); Pb free version also available



ORDERING INFORMATION

Order Number(s):

USB2223-NE-03 for 128 pin TQFP package

USB2223-NU-03 for 128 pin TQFP package (PB free)



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Table of Contents

Chapter 1	General Description	4
Chapter 2	Acronyms and Definitions	
	yms	
2.2 Definit	tions	5
Chapter 3	Pin Table	6
3.1 128-P	in Package	6
	in List Table	
3.2.1	128 Pin TQFP	7
	Pin Configuration	
4.1 128 P	in TQFP	8
Chapter 5	Block Diagram	9
Chapter 6	Pin Descriptions	10
	escriptions	
	Type Descriptions	
	Usage Table	
Chapter 7	DC Parameters	17
	num Guaranteed Ratings	
7.2 DC EI	ectrical Characteristics	17
Chapter 8	Package Outline	20
List of F	igures	
Figure 8.1 - 1	28 Pin TQFP Package	20
List of T		
	noutn Description	
	SB2223-03 Buffer Type Descriptions	
	PIO Usage	
	28 Pin TQFP Package Parameters	



Chapter 1 General Description

The USB2223-03 is a USB2.0 Bulk Only Mass Storage Class Peripheral Controller intended for supporting CompactFlash (CF and CF Ultra I/II) in True IDE Mode only, SmartMedia (SM), Memory Stick (MS), Memory Stick DUO (MSDUO) and Memory Stick Pro (MSPRO), Secure Digital (SD), and MultiMediaCard (MMC) flash memory devices. It provides a single chip solution for the most popular flash memory cards in the market.

The device consists of a USB2.0 PHY and SIE, buffers, Fast 8051 microprocessor with expanded scratchpad, and program SRAM, and CF, MS, SM and SD controllers. The SD controller supports both SD and MMC devices.

Provisions for external Flash Memory up to 64K bytes for program storage is provided.

12K bytes of scratchpad SRAM and 768 Bytes of program SRAM are also provided.

Fifteen GPIO pins are provided for indicators, external serial EEPROM for OEM id and system configuration information, and other special functions.

The internal ROM program is capable of implementing any combination of single or multi-LUN CF/SD/MMC/SM/MS reader functions with individual card power control and activity indication. SMSC also provides licenses** for Win98 and Win2K drivers and setup utilities. Note: Please check with SMSC for precise features and capabilities for the current ROM code release.

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Chapter 2 Acronyms and Definitions

2.1 Acronyms

SM: SmartMedia

SMC: SmartMedia Controller

FM: Flash Media

FMC: Flash Media Controller

CF: Compact Flash

CFC: CompactFlash Controller

SD: Secure Digital

SDC: Secure Digital Controller

MMC: MultiMediaCardMS: Memory Stick

MSC: Memory Stick ControllerTPC: Transport Protocol Code.ECC: Error Checking and CorrectingCRC: Cyclic Redundancy Checking

2.2 Definitions

Flash Media DMA UNIT (FMDU): The control logic in the flash media controller block as shown in the Block Diagram that support the data transfer from CFC, SMC, MSC and SDC to EP2 buffer directly.

SD/MMC: the built-in SD controller (SDC) supports both SD and MMC devices.

Flash Media Controller Data Multiplexer (FMC DATA MUX): The multiplexer to enable the different data path from the different flash media controllers (CFC, SMC, MSC and SDC).



Chapter 3 Pin Table

3.1 128-Pin Package

Table 3.1 - Pinout

Table 3.1 - Pinout							
CompactFlash INTERFACE (28 Pins)							
CF_D0	CF_D1	CF_D2	CF_D3				
CF_D4	CF_D5	CF_D6	CF_D7				
CF_D8	CF_D9	CF_D10	CF_D11				
CF_D12	CF_D13	CF_D14	CF_D15				
CF_nIOR	CF_nIOW	CF_IRQ	CF_nRESET				
CF_IORDY	CF_nCS0	CF_nCS1	CF_SA0				
CF_SA1	CF_SA2	CF_nCD1	CF_nCD2				
	SmartMedia INTER	RFACE (17 Pins)					
SM_D0	SM_D1	SM_D2	SM_D3				
SM_D4	SM_D5	SM_D6	SM_D7				
SM_ALE	SM_CLE	SM_nRE	SM_nWE				
SM nWP	SM nB/R	SM nCE	SM nCD				
SM_nWPS	_	_	_				
_	Memory Stick INTE	RFACE (7 Pins)	1				
MS_BS	MS SDIO/MS D0	MS SCLK	MS INS				
MS D1	MS D2	MS D3	_				
-	SD INTERFA	CE (7 Pins)	1				
SD_CMD	SD CLK	SD DATO	SD DAT1				
SD DAT2	SD DAT3	SD nWP	_				
_	USB INTERFA	CE (13 Pins)	1				
USB+	USB-	ATEST	RBIAS				
VDDP	VSSP	(2)VDDA	(2)VSSA				
VREG	XTAL1/CLKIN	XTAL2					
	MEMORY/IO INTER	RFACE (27 Pins)					
MA0	MA1	MA2	MA3				
MA4	MA5	MA6	MA7				
MA8	MA9	MA10	MA11				
MA12	MA13	MA14	MA15				
MD0	MD1	MD2	MD3				
MD4	MD5	MD6	MD7				
nMRD	nMWR	nMCE					
	MISC (18	Pins)					
nRESET	GPIO1	GPIO2	GPIO3				
GPIO4	GPIO5	GPIO6/ROMEN	GPIO7				
GPIO8	GPIO9	GPIO10	GPIO11				
GPIO12	GPIO13	GPIO14	GPIO15				
nTEST0	nTEST1						
	DIGITAL, POWER, GRO	OUND & NC (11 Pins)					
(3)VDDIO	(4)VSSIO	(2)VDDCORE	(2)VSSCORE				
	Total	128					
Total 128							



3.2 128 Pin List Table

3.2.1 128 Pin TQFP

PIN#	NAME	MA	PIN#	NAME	MA	PIN#	NAME	MA	PIN#	NAME	MA
1	MA0	8	33	MS_D2	8	65	CF_nCD2	-	97	ATEST	-
2	MA1	8	34	MS_D1	8	66	CF_IRQ	-	98	VDDP	
3	MA2	8	35	MS_D0	8	67	CF_IORDY	-	99	XTAL2	-
4	VDDIO		36	MS_SCLK	8	68	CF_nIOR	8	100	XTAL1	-
5	MA3	8	37	MS_BS	8	69	CF_nIOW	8	101	VSSP	
6	MA4	8	38	SD_nWP	-	70	CF_nRESET	8	102	VDDA(REF)	
7	MA5	8	39	VDDIO		71	CF_nCS0	8	103	RBIAS	-
8	MA6	8	40	SD_DAT0	8	72	CF_nCS1	8	104	VSSA(REF)	
9	MA7	8	41	SD_DAT1	8	73	CF_SA0	8	105	VDDA	
10	MA8	8	42	SD_DAT2	8	74	VDDIO		106	USB+	-
11	MA9	8	43	SD_DAT3	8	75	CF_SA1	8	107	USB-	-
12	MA10	8	44	SD_CMD	8	76	CF_SA2	8	108	VSSA	
13	MA11	8	45	SD_CLK	8	77	SM_D0	8	109	nRESET	-
14	MA12	8	46	CF_D0	8	78	SM_D1	8	110	VSSCORE	
15	MA13	8	47	CF_D1	8	79	VSSIO		111	nTEST0	-
16	VDDCORE		48	CF_D2	8	80	SM_D2	8	112	nTEST1	-
17	MA14	8	49	CF_D3	8	81	SM_D3	8	113	GPIO1	8
18	MA15	8	50	CF_D4	8	82	SM_D4	8	114	GPIO2	8
19	MD0	8	51	VSSIO		83	SM_D5	8	115	GPIO3	8
20	MD1	8	52	VSSCORE		84	SM_D6	8	116	GPIO4	8
21	MD2	8	53	CF_D5	8	85	SM_D7	8	117	GPIO5	8
22	MD3	8	54	CF_D6	8	86	SM_ALE	8	118	GPIO6/ROMEN	8
23	VSSIO		55	CF_D7	8	87	SM_CLE	8	119	GPIO7	8
24	MD4	8	56	CF_D8	8	88	SM_nRE	8	120	GPIO8	8
25	MD5	8	57	CF_D9	8	89	SM_nWE	8	121	GPIO9	8
26	MD6	8	58	CF_D10	8	90	SM_nWP	8	122	GPIO10	8
27	MD7	8	59	CF_D11	8	91	VDDCORE		123	GPIO11	8
28	nMRD	8	60	CF_D12	8	92	SM_nCE	8	124	VSSIO	
29	nMWR	8	61	CF_D13	8	93	VREG		125	GPIO12	8
30	nMCE	8	62	CF_D14	8	94	SM_nWPS	-	126	GPIO13	8
31	MS_INS	-	63	CF_D15	8	95	SM_nB/R	-	127	GPIO14	8
32	MS_D3	8	64	CF_nCD1	-	96	SM_nCD	-	128	GPIO15	8

Note 1: RBIAS is connected to the Analog Ground plane VSSA(REF) via a resistor.

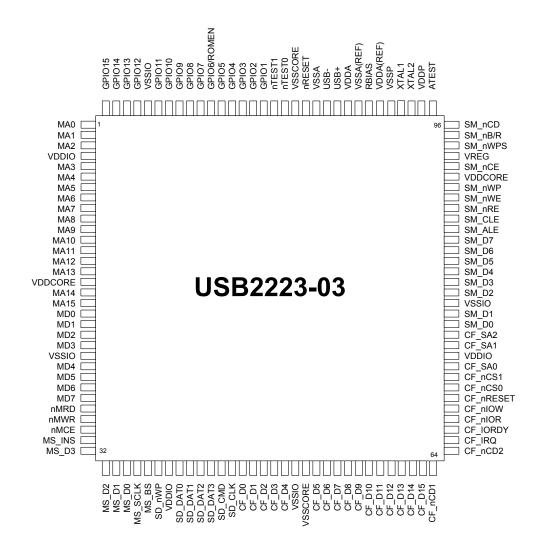
Note 2: When the internal 1.8V regulator is enabled, VDDCORE (91) and VDDP(98), MUST have a 10uf +/- 20%, (equivalent series resistance (ESR) <0.1ohm) bypass capacitor to VSSA.

Note 3: VDDA(REF) and VSSA(REF) are same as the VDDA and VSSA respectively.



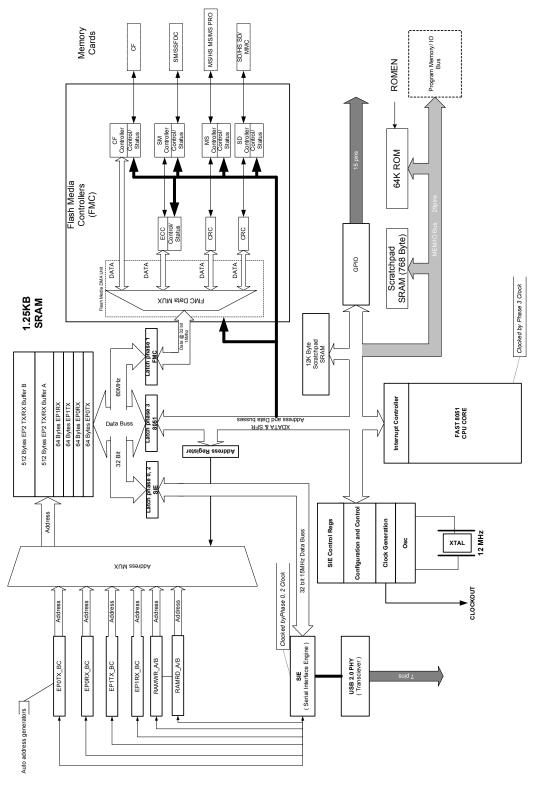
Chapter 4 Pin Configuration

4.1 128 Pin TQFP





Chapter 5 Block Diagram



DATASHEET

SMSC USB2223-03



Chapter 6 Pin Descriptions

This section provides a detailed description of each signal. The signals are arranged in functional groups according to their associated interface.

The "n" symbol in the signal name indicates that the active, or asserted state occurs when the signal is at a low voltage level. When "n" is not present before the signal name, the signal is asserted when at the high voltage level.

The terms assertion and negation are used exclusively. This is done to avoid confusion when working with a mixture of "active low" and "active high" signal. The term assert, or assertion indicates that a signal is active, independent of whether that level is represented by a high or low voltage. The term negate, or negation indicates that a signal is inactive.

6.1 Pin Descriptions

Table 6.1 - Pin Description

NAME	SYMBOL	BUFFER TYPE	DESCRIPTION					
	CompactFlash (In True IDE mode) INTERFACE							
CF Chip Select	CF_nCS1	O8	This pin is the active low chip select 1 signal for the CF ATA device					
CF Chip Select 0	CF_nCS0	O8	This pin is the active low chip select 0 signal for the task file registers of CF ATA device in the True IDE mode.					
CF Register Address 2	CF_SA2	O8	This pin is the register select address bit 2 for the CF device.					
CF Register Address 1	CF_SA1	O8	This pin is the register select address bit 1 for the CF device.					
CF Register Address 0	CF_SA0	O8	This pin is the register select address bit 0 for the CF device.					
CF Interrupt	CF_IRQ	IPD	This is the active high interrupt request signal from the CF device.					
CF Data 15-8	CF_D[15:8]	I/O8	The bi-directional data signals CF_D15-CF_D8 in True IDE mode data transfer. The bi-directional data signal has an internal weak pull-down resistor.					
CF Data7-0	CF_D[7:0]	1/08	The bi-directional data signals CF_D7-CF_D0 in the True IDE mode data transfer.					
			In the True IDE Mode, all of task file register operation occur on the CF_D[7:0], while the data transfer is on CF_D[15:0].					
			The bi-directional data signal has an internal weak pull-down resistor.					
IO Ready	CF_IORDY	IPU	This pin is active high input signal from CF card.					
CF Card Detection2	CF_nCD2	IPU	This card detection pin is connected to the ground on the CF device, when the CF device is inserted.					
CF Card Detection1	CF_nCD1	IPU	This card detection pin is connected to ground on the CF device, when the CF device is inserted.					

Datasheet



NAME	SYMBOL	BUFFER TYPE	DESCRIPTION
CF Hardware Reset	CF_nRESET	О8	This pin is an active low hardware reset signal to CF device.
CF IO Read	CF_nIOR	O8	This pin is an active low read strobe signal for CF device, when the CFC is enabled.
CF IO Write Strobe	CF_nIOW	O8	This pin is an active low write strobe signal for CF device, when the CFC is enabled.
		Smart	Media INTERFACE
SM Write Protect	SM_nWP	O8	This pin is an active low write protect signal for the SM device, when the SMC is enabled.
SM Address Strobe	SM_ALE	O8	This pin is an active high Address Latch Enable signal for the SM device, when the SMC is enabled.
SM Command Strobe	SM_CLE	O8	This pin is an active high Command Latch Enable signal for the SM device, when the SMC is enabled.
SM Data7-0	SM_D[7:0]	I/O8	These pins are the bi-directional data signal SM_D7-SM_D0, when the SMC is enabled.
SM Read Enable	SM_nRE	O8	This pin is an active low read strobe signal for SM device, when SMC is enabled.
SM Write Enable	SM_nWE	O8	This pin is an active low write strobe signal for SM device, when SMC is enabled.
SM Write Protect Switch	SM_nWPS	IPU	A write-protect seal is detected, when this pin is low.
SM Busy or Data Ready	SM_nB/R	I	This pin is connected to the BSY/RDY pin of the SM device.
			An external pull-up resistor is required on this signal. The pull-up resistor should be attached to the power of SM/NAND flash device.
SM Chip Enable	SM_nCE	O8	This pin is the active low chip enable signal to the SM device.
SM Card Detection	SM_nCD	IPU	This is the card detection signal from SM device to indicate if the device is inserted.
		MEMORY	STICK INTERFACE
MS Bus State	MS_BS	O8	This pin is connected to the BS pin of the MS device.
			It is used to control the Bus States 0, 1, 2 and 3 (BS0, BS1, BS2 and BS3) of the MS device.
MS System Data In/Out	MS_SDIO /MS_D0	I/O8	This pin is a bi-directional data signal for the MS device. Most significant bit (MSB) of each byte is transmitted first by either MSC or MS device.
			The bi-directional data signal has an internal weak pull-down resistor.
MS System Data In/Out	MS_D1	IO8PD	This pin is a bi-directional data signal for the MS device.
			The bi-directional data signal has an internal weak pull-down resistor that is internally controlled.
MS System Data In/Out	MS_D[3:2]	I/O8	This pin is a bi-directional data signal for the MS device.
			The bi-directional data signal has an internal weak pull-down resistor.
MS Card Insertion	MS_INS	IPU	This pin is the card detection signal from the MS device to indicate, if the device is inserted.



NAME	SYMBOL	BUFFER TYPE	DESCRIPTION
MS System CLK	MS_SCLK	O8	This pin is an output clock signal to the MS device.
		SE	INTERFACE
SD Data3-0	SD_DAT[3:0]	I/O8	These are bi-directional data signals.
SD Clock	SD_CLK	O8	This is an output clock signal to SD/MMC device.
SD Command	SD_CMD	I/O8	This is a bi-directional signal that connects to the CMD signal of SD/MMC device.
SD Write Protected	SD_nWP	IPD	This pin is Write Protect Switch input signal with an internal weak pull-down.
l .		US	B INTERFACE
USB Bus Data	USB- USB+	IO-U	These pins connect to the USB bus data signals.
USB Transceiver Bias	RBIAS	I	A 12.0K Ω ± 1% resistor is attached from ground to this pin to set the transceiver's internal bias currents.
Analog Test	ATEST	IOA	This signal is used for testing the analog section of the chip and should be connected to VDDA for normal operation.
1.8v Analog Power	VDDP		1.8v Analog Power
T OWE!			This pin MUST have a 10uf +/- 20%, (equivalent series resistance (ESR) <0.10hm) bypass capacitor to VSSA. This capacitor should be placed as close to the pin as possible.
Analog Ground Reference	VSSP		Analog Ground Reference for 1.8v Analog power.
3.3v Analog Power	VDDA		3.3v Analog Power
Analog Ground Reference	VSSA		Analog Ground Reference for 3.3v Analog Power.
1.8v Voltage Regulator for USB PHY	VREG		This pin is connected to 3.3v.
Crystal Input/External	XTAL1/ CLKIN	ICLKx	12Mhz Crystal or external clock input.
Clock Input	OLIVIIV		This pin can be connected to one terminal of the crystal or can be connected to an external 12Mhz clock when a crystal is not used.
Crystal Output	XTAL2	OCLKx	12Mhz Crystal
			This is the other terminal of the crystal, or left open when an external clock source is used to drive XTAL1/CLKIN. It may not be used to drive any external circuitry other than the crystal circuit.
		MEMOI	RY/IO INTERFACE
Memory Data Bus	MD[7:0]	IO8	When using external program memory, these signals are used to transfer data between the internal CPU and the external program memory.
			When using internal program ROM, internal weak pull up resistors are activated to prevent these pins from floating.

Datasheet



NAME	SYMBOL	BUFFER TYPE	DESCRIPTION
Memory Address Bus	MA[15:0]	O8	These signals address memory locations within the external memory.
Memory Read Strobe	nMWR	O8	Program Memory Write; active low
Memory Read Strobe	nMRD	O8	Program Memory Read; active low
Memory Chip Enable	nMCE	O8	Program Memory Chip Enable; active low. This signal is asserted, when the device is not is SUSPEND mode.
			Note: This signal is held in a logic 'high' state (inactive) during nRESET assertion.
			MISC
GPIO6, ROMEN and	GPIO6 /ROMEN	I/O8PU	This pin has an internal weak pullup resistor that can be enabled or disabled by the state of nRESET.
RXD			The pullup is enabled when nRESET is active.
			The pullup is disabled, when the nRESET is inactive (some clock cycles later, after the rising edge of nRESET).
			The state of this pin is latched internally on the rising edge of nRESET to determine if internal or external program memory is used.
			The state latched is stored in ROMEN bit of GPIO_IN1 register. After the rising edge of nRESET, this pin may be used as GPIO6 or RXD.
			When pulled low via an external weak pulldown resistor, an external program memory should be connected to the memory data bus. The USB2223-03 uses this external bus for program execution.
			When this pin is left unconnected or pulled high by a weak pullup resistor, the USB2223-03 uses the internal ROM for program execution.
			This pin's function while operating from internal ROM is shown in Table 6.3 - GPIO Usage.
General Purpose I/O	GPIO1	I/O8	This pin may be used either as input, edge sensitive interrupt input, or output.
			This pin's function while operating from internal ROM is shown in Table 6.3 - GPIO Usage.
General Purpose I/O	GPIO2	I/O8	This pin may be used either as input, edge sensitive interrupt input, or output.
			This pin's function while operating from internal ROM is shown in Table 6.3 - GPIO Usage.
General Purpose I/O	GPIO3	I/O8	This pin may be used either as input, edge sensitive interrupt input, or output.
			This pin's function while operating from internal ROM is shown in Table 6.3 - GPIO Usage.



NAME	SYMBOL	BUFFER TYPE	DESCRIPTION
General Purpose I/O	GPIO4	1/08	This pin may be used either as input, edge sensitive interrupt input, or output.
			This pin's function while operating from internal ROM is shown in Table 6.3 - GPIO Usage.
General Purpose I/O	GPIO5	I/O8	This pin may be used either as input, edge sensitive interrupt input, or output.
			This pin's function while operating from internal ROM is shown in Table 6.3 - GPIO Usage.
General Purpose I/O	GPIO7	I/O8	This pin may be used either as input, edge sensitive interrupt input, or output.
			This pin's function while operating from internal ROM is shown in Table 6.3 - GPIO Usage.
General	GPIO[15:8]	I/O8	These pins may be used either as input, or output.
Purpose I/O			These pins' functions while operating from internal ROM are shown in Table 6.3 - GPIO Usage.
RESET input	nRESET	IS	This active low signal is used by the system to reset the chip. The active low pulse should be at least $1\mu s$ wide.
TEST Input	nTEST[0:1]	1	These signals are used for testing the chip. User should normally tie them high externally.
	DIGIT	AL POWER, G	ROUNDS, and NO CONNECTS
1.8v Digital Core Power	VDDCORE		+1.8V Core power
			All VDDCORE pins must be connected together on the circuit board.
			Pin 91 MUST have a 10uf +/- 20%, (equivalent series resistance (ESR) <0.10hm) bypass capacitor to VSSA, and this capacitor should be placed as close to the pin as possible.
3.3v Digital I/O power	VDDIO		+3.3V I/O power
VDDCORE reference ground	VSSCORE		VDDCORE ground Reference
VDDIO reference ground	VSSIO		VDDIO ground reference

Note 1: Hot-insertion capable card connectors are required for all of flash medias. It is required for SD connector to have Write Protect switch. This allows the chip to detect MMC card.

Note 2: nMCE is normally asserted except when the system is in standby mode.



6.2 Buffer Type Descriptions

Table 6.2 - USB2223-03 Buffer Type Descriptions

BUFFER	DESCRIPTION
I	Input
IPU	Input with controlled internal weak pull-up resistor.
IPD	Input with controlled internal weak pull-down resistor.
IS	Input with Schmitt trigger
I/O8	Input/Output with 8mA drive
I/OD8	Input/Open drain output 8mA sink
O8	Output with 8mA drive
I/O8PU	Input/Output with 8mA drive controlled weak pull-up resistor
I/O8PD	Input/Output with 8mA drive controlled weak pull-down resistor
ICLKx	XTAL clock input
OCLKx	XTAL clock output
I/O-U	Analog Input/Output Defined in USB specification
O-U	Analog Output
I-U	Analog Input
OIA	Special analog Input/Output

6.3 **GPIO Usage Table**

Table 6.3 - GPIO Usage

NAME	ACTIVE LEVEL	SYMBOL	DESCRIPTION AND NOTE
GPIO1	H/L	ACT	Media Activity LED
GPIO2	Н	EE_CS	Serial EE PROM chip select
GPIO3	Н	V_BUS	USB V bus detect
GPIO4	Н	EE_DIN/EE_DOUT	Serial EE PROM input/output
GPIO5	Н	HSLED/SD_CD	High Speed LED Indicator Output/ SD Card Detect Input. The function of this pin is set by programming of the attribute bits. In the production ROM version (-03), the default is to be used as HS LED output
GPIO6	Н	A16 (external ROM only) /ROMEN	Int/Ext ROM select. External program memory A16 address line connect for DFU.
GPIO7	Н	EE_CLK	Serial EE PROM clock output
GPIO8	L	MS Power Control	Memory Stick Card Power Control
GPIO9	L	CF Power Control	CompactFlash Card Power Control
GPIO10	L	SM Power Control	SmartMedia Card Power Control
GPIO11	L	SD Power Control	SD/MMC Card Power Control
GPIO12	Н	MS/MSPro Activity	Memory Stick(/Pro) Activity Indicator





NAME	ACTIVE LEVEL	SYMBOL	DESCRIPTION AND NOTE
GPIO13	Н	CF Activity	CompactFlash Activity Indicator
GPIO14	Н	SM Activity	SmartMedia Activity Indicator
GPIO15	Н	SD/MMC Activity	SD/MMC Activity Indicator



Chapter 7 DC Parameters

7.1 Maximum Guaranteed Ratings

Operating Temperature Range	0°C to +70°C
Storage Temperature Range	55° to +150°C
Lead Temperature Range (soldering, 10 seconds)	+325°C
Positive Voltage on any pin, with respect to Ground	5.5V
Negative Voltage on any pin, with respect to Ground	0.3V
Maximum V _{DD} , V _{DDP}	+2.5V
Maximum V _{DDIO} , V _{DDA}	+4.0V

^{*} Stresses above the specified parameters could cause permanent damage to the device. This is a stress rating only and functional operation of the device at any other condition above those indicated in the operation sections of this specification is not implied.

Notes:

- When powering this device from laboratory or system power supplies, it is important that the Absolute Maximum Ratings not be exceeded or device failure can result. Some power supplies exhibit voltage spikes on their outputs when the AC power is switched on or off. In addition, voltage transients on the AC power line may appear on the DC output. When this possibility exists, it is suggested that a clamp circuit be used.
- The name "VDD" is the same as VDDCORE

7.2 DC Electrical Characteristics

 $(T_A = 0^{\circ}C - 70^{\circ}C, V_{DDIO}, V_{DDA} = +3.3 V \pm 10\%, V_{DD}, V_{DDP} = +1.8 V \pm 10\%,)$

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	COMMENTS
I Type Input Buffer						
Low Input Level	V _{ILI}			0.8	V	TTL Levels
High Input Level	V _{IHI}	2.0			V	
IS Type Input Buffer						
Low Input Level	V _{ILI}			0.8	V	TTL Levels
High Input Level	V _{IHI}	2.0			V	
Hysteresis	V_{HYSI}		500		mV	



PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	COMMENTS
ICLK Input Buffer						
Low Input Level	V _{ILCK}			0.4	V	
High Input Level	V _{IHCK}	2.2			V	
Input Leakage						
(All I and IS buffers)						
Low Input Leakage	I _{IL}	-10		+10	uA	V _{IN} = 0
High Input Leakage	I _{IH}	-10		+10	uA	$V_{IN} = V_{DDIO}$
O8 Type Buffer						
Low Output Level	V _{OL}			0.4	V	I _{OL} = 8 mA @ V _{DDIO} = 3.3V
High Output Level	V _{OH}	2.4			V	I _{OH} = -4mA @ V _{DDIO} = 3.3V
Output Leakage	I _{OL}	-10		+10	uA	$V_{IN} = 0$ to V_{DDIO} (Note 7.1)
I/O8 Type Buffer						
Low Output Level	V _{OL}			0.4	V	I _{OL} = 8 mA @ V _{DDIO} = 3.3V
HIGH OUTPUT LEVEL	V _{OH}	2.4			V	I _{OH} = -4 mA @ V _{DDIO} = 3.3V
Output Leakage	I _{OL}	-10		+10	μA	V _{IN} = 0 to V _{DDIO} (Note 7.1)
I/O12 Type Buffer						
Low Output Level	V _{OL}			0.4	V	I _{OL} = 12 mA @ V _{DDIO} = 3.3V
High Output Level	V _{OH}	2.4			V	I _{OH} = -6mA @ V _{DDIO} = 3.3V
Output Leakage	I _{OL}	-10		+10	μΑ	V _{IN} = 0 to V _{DDIO} (Note 7.1)

Datasheet



PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	COMMENTS
I/O24 Type Buffer						
Low Output Level	V _{OL}			0.4	V	I _{OL} = 24 mA @ V _{DDIO} = 3.3V
High Output Level	V _{OH}	2.4			V	I _{OH} = -12 mA @ V _{DDIO} = 3.3V
Output Leakage	I _{OL}	-10		+10	μA	$V_{IN} = 0$ to V_{DDIO} (Note 7.1)
IO-U						
Supply Current Unconfigured	I _{CCINIT}		45	60	mA	@ V_{DD} , $V_{DDP} = 1.8V$
			10	20	mA	$@V_{DDIO}, V_{DDA} = 3.3V$
Supply Current Active	I _{CC}		35	60	mA	@ V_{DD} , $V_{DDP} = 1.8V$
(Full Speed)			15	30	mA	$@V_{DDIO}, V_{DDA} = 3.3V$
Supply Current Active	I _{cc}		45	70	mA	@ V_{DD} , $V_{DDP} = 1.8V$
(High Speed)			15	30	mA	$@V_{DDIO}, V_{DDA} = 3.3V$
Supply Current Standby	I _{CSBY}		160	180	μΑ	@ V_{DD} , $V_{DDP} = 1.8V$
			215	240	μA	\bigcirc V _{DDIO,} V _{DDA} = 3.3V

Note 7.1 Output leakage is measured with the current pins in high impedance.

CAPACITANCE $T_A = 25^{\circ}C$; fc = 1MHz; $V_{DD,}V_{DDP} = 1.8V$

		LIMITS				
PARAMETER	SYMBOL	MIN	TYP	MAX	UNIT	TEST CONDITION
Clock Input Capacitance	C _{IN}			20	pF	All pins except USB
Input Capacitance	C _{IN}			10	pF	pins (and pins
Output Capacitance	C _{OUT}			20	pF	under test tied to AC ground)



Chapter 8 Package Outline

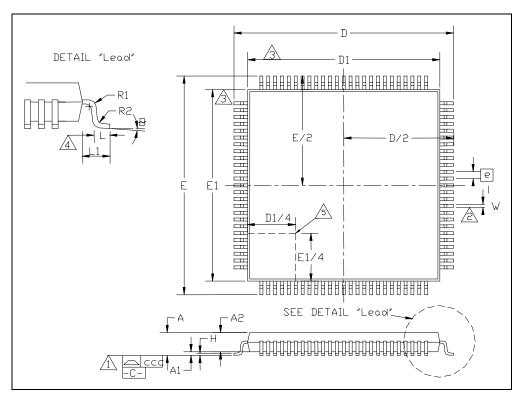


Figure 8.1 - 128 Pin TQFP Package

Table 8.1 - 128 Pin TQFP Package Parameters

	MIN	NOMINAL	MAX	REMARKS
Α	~	~	1.20	Overall Package Height
A1	0.05	~	0.15	Standoff
A2	0.95	~	1.05	Body Thickness
D	15.80	~	16.20	X Span
D1	13.80	~	14.20	X body Size
Е	15.80	~	16.20	Y Span
E1	13.80	~	14.20	Y body Size
Н	0.09	~	0.20	Lead Frame Thickness
L	0.45	0.60	0.75	Lead Foot Length
L1	~	1.00	~	Lead Length
е		0.40 Basic		Lead Pitch
θ	0°	~	7°	Lead Foot Angle
W	0.13	0.18	0.23	Lead Width
R1	0.08	~	~	Lead Shoulder Radius
R2	0.08	~	0.20	Lead Foot Radius
ССС	~	~	0.08	Coplanarity

Notes:

- 1) Controlling Unit: millimeter.
- 2) Tolerance on the true position of the leads is ± 0.035 mm maximum.
- 3) Package body dimensions D1 and E1 do not include the mold protrusion. Maximum mold protrusion is 0.25 mm.
- 4) Dimension for foot length L measured at the gauge plane 0.25 mm above the seating plane.
- 5) Details of pin 1 identifier are optional but must be located within the zone indicated.